

3 CHANNEL DIFFERENTIAL AMPLIFIER-COMPARATOR

ET9570LIT

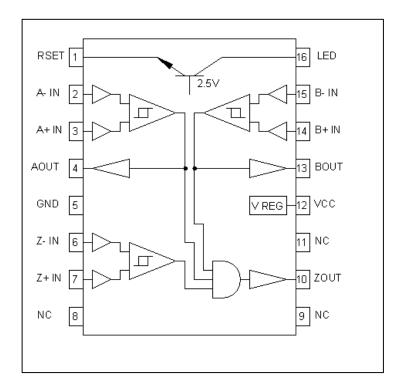
(Lower hysteresis version of standard ET9570)

FEATURES

- Supply Voltage Range 4.5V to 30V
- Operation to 1MHz
- Designed for photodiode inputs
- Index gated by A and B channels
- Current sink for LED drive (see application note APP-D2)
- Outputs short circuit protected
- 25mA peak drive current
- Comparator hysteresis only 1.1 : 1

APPLICATIONS

- High Speed Optical Encoders
- Industrial Controls



DESCRIPTION

These devices are specifically designed as receiver circuits for the photodiode signals available in optical encoders. Connect the anode of the photodiodes to the input pins, with the cathode(s) connected to Vcc for reverse-bias operation. The input amplifiers have a dynamic range of nearly 1000:1, and allow contrast ratios of encoded signal to www.common.mode signal of as low as 2:1. Differential inputs enhance noise rejection and performance over temperature. Gating of the Z channel provides synchronization of the reference pulse to the data channel phasing. Hysteresis ratio of comparators is 1.1:1, instead of the 1.25:1 on the standard device.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min.	Max.	Units	Ref.
Operating Temperature	T _A	-40	125	°C	Note 1
Range					
Supply Voltage Range	V _{CC}	4.5	30	V	

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ELECTRICAL CHARACTERISTICS

Unless otherwise specified, typical values given at V_{CC}=12V, T_A = 25°C, with LED and RSET open.

Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Supply Current	Icc1	4.5	7.2	11.5	_	Vcc = 4.5 V
	lcc2	5.0	8.0	12.5	mA	Vcc = 30.0V
Input Common Mode Voltage	Vсм		1.35		V	
Average Photocurrent Input	I _{IA}	0.066	0.3	40	μA	Each input
Peak Photocurrent Input	I _{IP}	0.13	0.5	60	μA	Each input
Dark Cell Level	I _{ID}	0.02	0.1	20	μA	Each input
Photocurrent Contrast Ratio	I _{IR}	2:1	5:1			Peak:Dark Cell
Comparator Threshold			1.1:1			Ratio of Differential
						Inputs
Output High Level Voltage	V _{OH}	2.5	3.0		V	$I_{OH} = -4mA, V_{CC} = 4.5V$
		28.0	28.5			$I_{OH} = -4mA, V_{CC} = 30V$
Output Low Level Voltage	V_{OL}		199	400	mV	$V_{CC} = 4.5V-30V$
						$I_{OL} = 8mA$
Output Short-Circuit Current	Ios	15	25	50	mA	$V_{CC} = 5V$, $V_{OUT} = 0V$
Driving High (All Outputs)						
Output Short-Circuit Current	Ios	30	70	120	mA	$V_{CC} = 5V$, $V_{OUT} = 5V$
Driving Low (All Outputs)						
RSET Voltage	V_{RSET}	1.3	1.7	2.1	V	R = 180 ohms

AC SWITCHING CHARACTERISTICS

Values given at $V_{CC} = 5V$, $T_A = 25$ °C, $C_L = 15$ pF on all outputs.

Parameters	Symbol	Min.	Тур.	Max	Units	Test Conditions
Pre-Amplifier Bandwidth	BW _{PA}		900		KHz	Photocurrent = 1µA Minimum
Propagation delay from Comparator Input to Output	T _{PD}		850		ns	
Output Rise Time	T _R		100		ns	
Output Fall Time	T _F		20		ns	

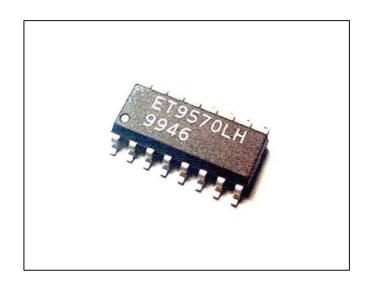
NOTES:

www.DataSheet4U.com

1. This is not a test parameter, but for information only.

PACKAGE SUFFIX

Chip Only -C 16 Lead SOIC -SOP



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